



IRF9640S Information



For Reference Only

Part Number IRF9640S

Manufacturer Vishay Siliconix

Category Discrete Semiconductor Products
Transistors - FETs, MOSFETs - Single

Description MOSFET P-CH 200V 11A D2PAK

Package TO-263-3, D2Pak (2 Leads + Tab), TO-263AB

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



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Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









IRF9640S Specifications

Manufacturer Part NumberIRF9640SManufacturerVishay SiliconixCategoryDiscrete Semiconductor ProductsTransistors - FETs, MOSFETs - SinglePackageTO-263-3, D2Pak (2 Leads + Tab), TO-263ABSeries-FET TypeP-ChannelTechnologyMOSFET (Metal Oxide)Drain to Source Voltage (Vdss)200VCurrent - Continuous Drain (Id) @ 25°C11A (Tc)Drive Voltage (Max Rds On, Min Rds On)10VVgs(th) (Max) @ Id4V @ 250μA	
Category Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single Package TO-263-3, D2Pak (2 Leads + Tab), TO-263AB Series - FET Type P-Channel Technology MOSFET (Metal Oxide) Drain to Source Voltage (Vdss) Current - Continuous Drain (Id) @ 25°C Drive Voltage (Max Rds On, Min Rds On) Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single TO-263-3, D2Pak (2 Leads + Tab), TO-263AB 200V P-Channel Technology MOSFET (Metal Oxide) 10V	
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Drive Voltage (Max Rds On, Min Rds On) 10V	
Vgs(th) (Max) @ Id 4V @ 250μA	
Gate Charge (Qg) (Max) @ Vgs 44nC @ 10V	
Input Capacitance (Ciss) (Max) @ Vds 1200pF @ 25V	
Vgs (Max) ±20V	
FET Feature -	
Power Dissipation (Max) 3W (Ta), 125W (Tc)	
Rds On (Max) @ Id, Vgs 500 mOhm @ 6.6A, 10V	
Operating Temperature $-55^{\circ}\text{C} \sim 150^{\circ}\text{C} \text{ (TJ)}$	
Mounting Type Surface Mount	
Supplier Device Package D2PAK	
Package / Case TO-263-3, D2Pak (2 Leads + Tab), TO-263AB	
Report	rrors?

IRF9640S Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

IRF9640S Payment Methods



















IRF9640S Shipping Methods













If you have any question about IRF9640S, please do not hesitate to contact us!

Website: https://www.heisener.com E-mail: salesdept@heisener.com